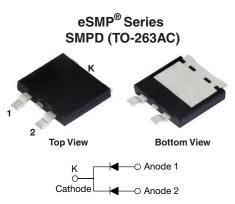
### Vishay Semiconductors

Ultrafast Rectifier, 2 x 5 A FRED Pt<sup>®</sup>



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### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	1 V				
t <sub>rr</sub>	35 ns				
T <sub>J</sub> max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Common cathode				

### FEATURES

- Ultrafast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM / CCM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V <sub>RRM</sub>		600	V		
Average restified forward average	per device	I <sub>F(AV)</sub>	T _ 152 °C	10			
Average rectified forward current	per diode		T <sub>solder pad</sub> = 153 °C	5	А		
Non repetitive peak aurea aureant				110	A		
Non-repetitive peak surge current	per diode	IFSM	$T_J = 25 \ ^{\circ}C, 6 \ ms$ square pulse	60			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage, per diode	V <sub>F</sub>	I <sub>F</sub> = 5 A	-	1.2	1.5	V	
		I <sub>F</sub> = 5 A, T <sub>J</sub> = 150 °C	-	1	1.25		
Reverse leakage current, per diode	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	3	μA	
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	15	150		
Junction capacitance, per diode	CT	V <sub>R</sub> = 600 V	-	6	-	pF	

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RoHS

COMPLIANT

HALOGEN



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## **Vishay Semiconductors**

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$	A/ $\mu$ s, V <sub>R</sub> = 30 V	-	35	-	
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A,	-	-	35		
		T <sub>J</sub> = 25 °C		-	45	-	A nC
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 5 A, dI <sub>F</sub> /dt = 500 A/µs, V <sub>B</sub> = 400 V	-	70	-	
Deals receiver a surrent		T <sub>J</sub> = 25 °C		-	7	-	
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	10	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	1 ''	-	160	-	
		T <sub>J</sub> = 125 °C		-	370	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	+175	°C	
Thermal resistance, per diode junction to mount	R <sub>thJM</sub>		-	2.4	3.3	°C/W	
Approximate weight				0.55		g	
Approximate weight				0.02		oz.	
Marking device		Case style SMPD (TO-263AC)		10CE	DU06		



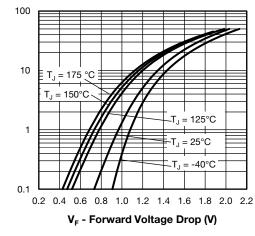


Fig. 1 - Typical Forward Voltage Drop Characteristics

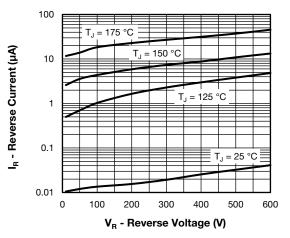


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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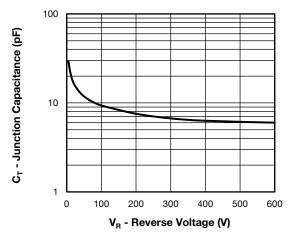


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

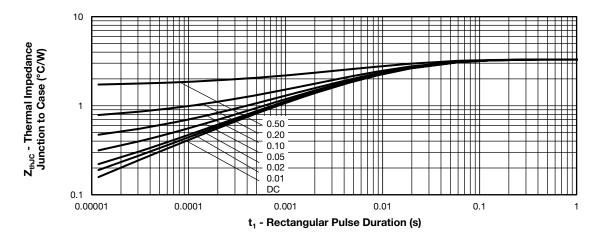
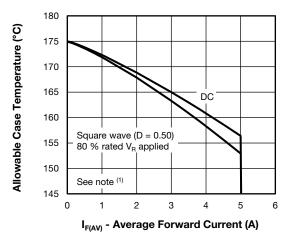
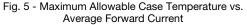


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



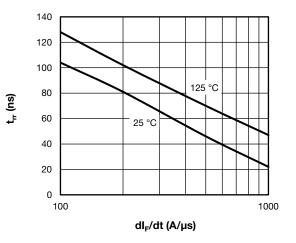
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#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times V_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/D) \mbox{ (see fig. 5);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{rated } V_{R} \end{array}$ 



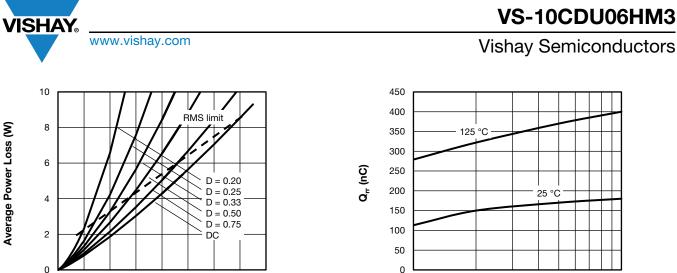


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I<sub>F(AV)</sub> - Average Forward Current (A) Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

2 3 4 5 6 7 8

0 1

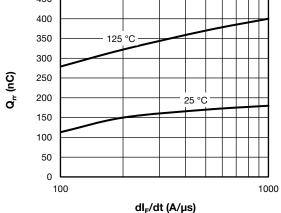


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

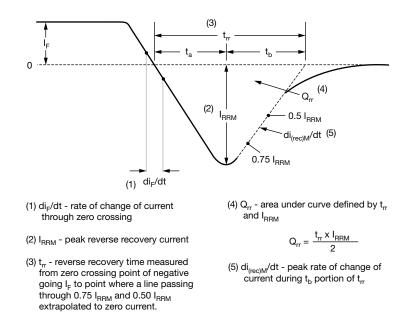


Fig. 9 - Reverse Recovery Waveform and Definitions

## Vishay Semiconductors

**ORDERING INFORMATION TABLE** 

Device code	vs-	10	с	D	U	06	н	М3
		(2)	(3)	(4)	(5)	6	$\overline{7}$	(8)
	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	Ċ	Ċ	$\bigcirc$	$\bigcirc$
	1	- Visl	hay Sen	nicondu	ctors pr	oduct		
	2	- Cur	rent rati	ng (10 A	4)			
	3	- Circ	cuit con	figuratio	n:			
		C =	commo	on catho	de			
	4	- D=	SMPD	packag	е			
	5	- Pro	cess typ	be,				
		U =	ultrafas	t recove	ery			
	6	- Vol	tage co	de (06 =	600 V)			
	7	- H=	AEC-Q	101 qua	alified			
	8	- M3	= halog	en-free,	RoHS-	complia	ant, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-10CDU06HM3/I	2000	2000	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95604					
Part marking information	www.vishay.com/doc?95566					
Packaging information	www.vishay.com/doc?88869					

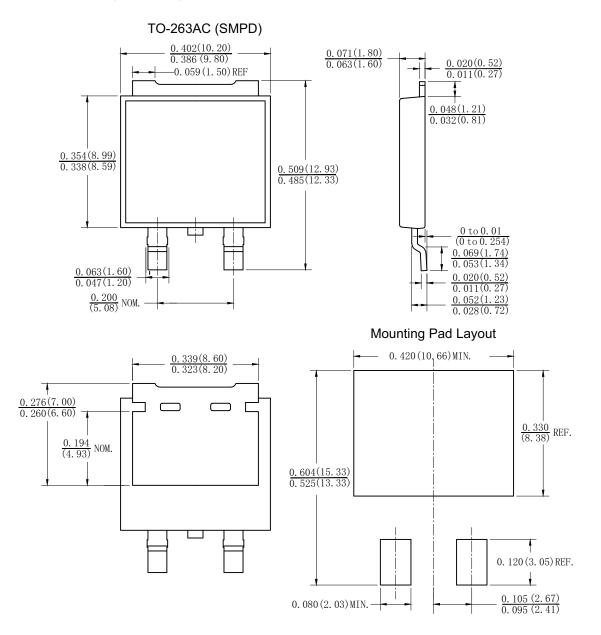






TO-263AC (SMPD)

### **DIMENSIONS** in inches (millimeters)





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